Transistors Panasonic

MSG330C4

SiGe HBT type

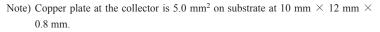
For low-noise RF amplifier

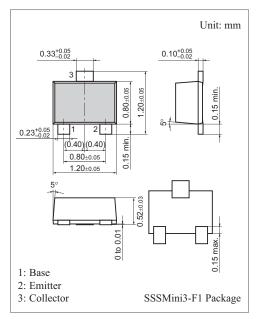
■ Features

- Compatible between high breakdown voltage and high cutoff frequency
- Low-noise, high-gain amplification
- \bullet Suitable for high-density mounting and downsizing of the equipment for Ultraminiature package 0.8 mm imes 1.2 mm (height 0.52 mm)

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	9	V	
Collector-emitter voltage (Base open)	V _{CEO}	6	V	
Emitter-base voltage (Collector open)	V _{EBO}	1	V	
Collector current	I_{C}	100	mA	
Collector power dissipation *	P _C	100	mW	
Junction temperature	T _j	125	°C	
Storage temperature	T _{stg}	-55 to +125	°C	





Marking Symbol: 4Y

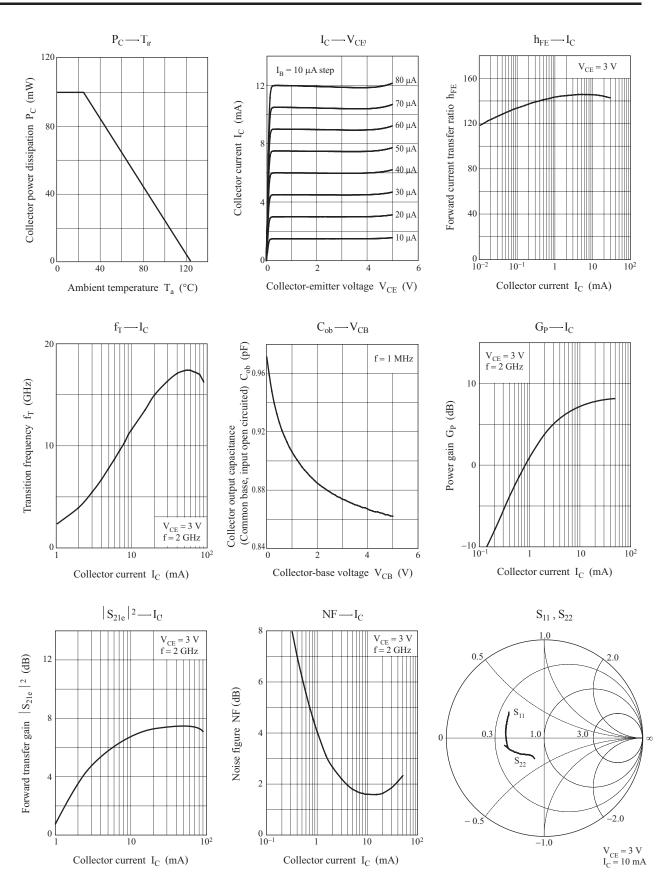
■ Electrical Characteristics $T_a = 25$ °C±3°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 9 \text{ V}, I_{E} = 0$			1	μΑ
Collector-emitter cutoff current (Base open)	I_{CEO}	$V_{CE} = 6 \text{ V}, I_{B} = 0$			1	μΑ
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 1 \text{ V, } I_{C} = 0$			1	μΑ
Forward current transfer ratio	h_{FE}	$V_{\rm CH} = 3 \text{ V}, I_{\rm C} = 15 \text{ mA}$	100		220	_
Transition frequency *	f_T	$V_{CH} = 3 \text{ V}, I_{CI} = 30 \text{ mA}, f = 2 \text{ GHz}$		16		GHz
Forward transfer gain *	$ S_{21e} ^2$	$V_{CE} = 3 \text{ V}, I_{CI} = 30 \text{ mA}, f = 2 \text{ GHz}$	5.0	8.0		dB
Noise figure *	NF	$V_{CE} = 3 \text{ V}, I_{CI} = 15 \text{ mA}, f = 2 \text{ GHz}$		1.6	2.2	dB
Collector output capacitance (Common base, input open circuited) *	C _{ob}	$V_{CB} = 3 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$		0.8	1.1	pF

 $Note) \ 1. \ Measuring \ methods \ are \ based \ on \ JAPANESE \ INDUSTRIAL \ STANDARD \ JIS \ C \ 7030 \ measuring \ methods \ for \ transistors.$

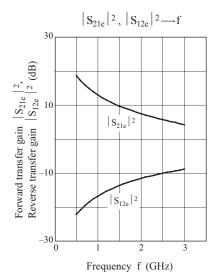
- 2. Observe precautions for handling. Electrostatic sensitive devices.
- 3. *: Verified by random sampling

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Panasonic MSG330C4



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